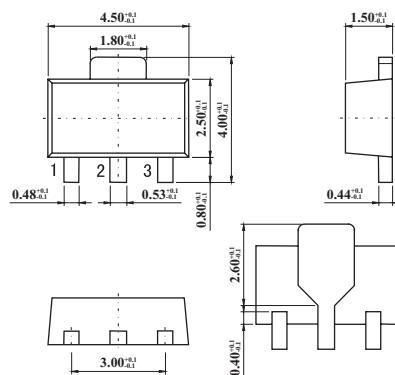

**SOT-89**


## Features

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCX51...BCX53(PNP)

## Ordering Information

Dimensions in inches and (millimeters)

Type No.	Marking	Package Code
BCX54	BA	SOT-89
BCX54-10	BC	SOT-89
BCX54-16	BD	SOT-89
BCX55	BE	SOT-89
BCX55-10	BG	SOT-89
BCX55-16	BM	SOT-89
BCX56	BH	SOT-89
BCX56-10	BK	SOT-89
BCX56-16	BL	SOT-89

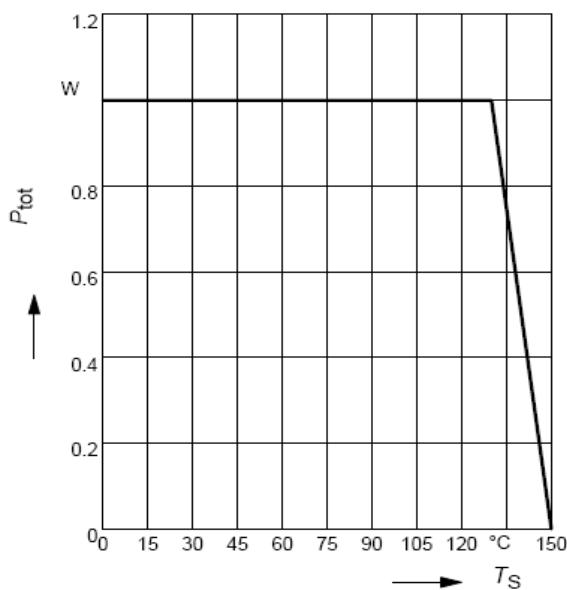
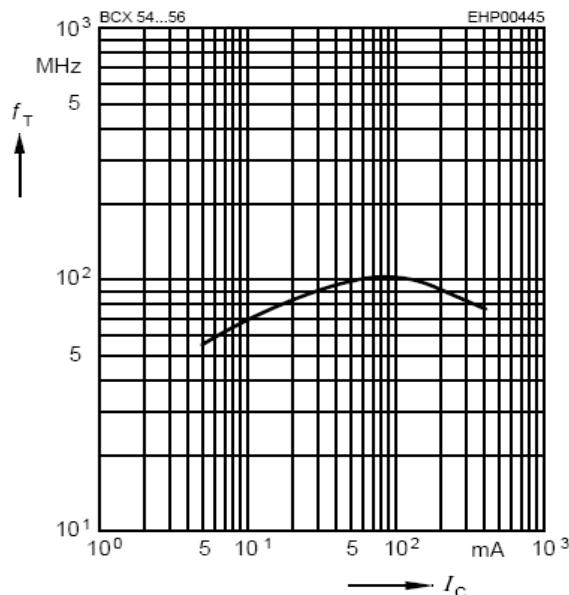
## MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	BCX54	45
		BCX55	60
		BCX56	100
V <sub>CEO</sub>	Collector-Emitter Voltage	BCX54	45
		BCX55	60
		BCX56	80
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	DC Collector Current	1	A
I <sub>CM</sub>	Peak Collector Current	1.5	A
I <sub>B</sub>	Base current	100	mA
I <sub>BM</sub>	Peak base current	200	mA
P <sub>tot</sub>	Total power dissipation, T <sub>S</sub> =130°C	1	W
T <sub>j, T<sub>stg</sub></sub>	Junction and Storage Temperature	-65 to +150	°C

ELECTRICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified

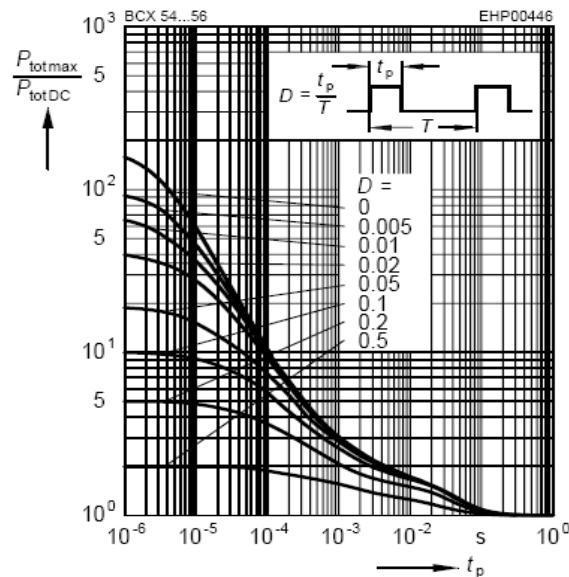
Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C=100\mu\text{A} I_B=0$ BCX54 $I_C=10\text{mA} I_B=0$ BCX55 $I_C=10\text{mA} I_B=0$ BCX56	45		V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C=10\mu\text{A} I_E=0$ BCX54 $I_C=10\mu\text{A} I_E=0$ BCX55 $I_C=10\mu\text{A} I_E=0$ BCX56	45		V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E=10\mu\text{A} I_C=0$	5		V
Collector cut-off current	$I_{\text{CBO}}$	$V_{\text{CB}}=30\text{V} I_E=0$		100	nA
		$V_{\text{CB}}=30\text{V} I_E=0, T_a=150^\circ\text{C}$		20	$\mu\text{A}$
DC current gain	$h_{\text{FE}}$	$V_{\text{CE}}=2\text{V} I_C=5\text{mA}$ $V_{\text{CE}}=2\text{V} I_C=150\text{mA}$ $V_{\text{CE}}=2\text{V} I_C=500\text{mA}$	25	250	
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	$I_C=500\text{mA} I_B=50\text{mA}$		0.5	V
Base-emitter voltage	$V_{\text{BE}}$	$I_C=500\text{mA}, V_{\text{CE}}=2\text{V}$		1	V
Transition frequency	$f_T$	$V_{\text{CE}}=10\text{V}, I_C=50\text{mA}, f=20\text{MHz}$	100		MHz

TYPICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified

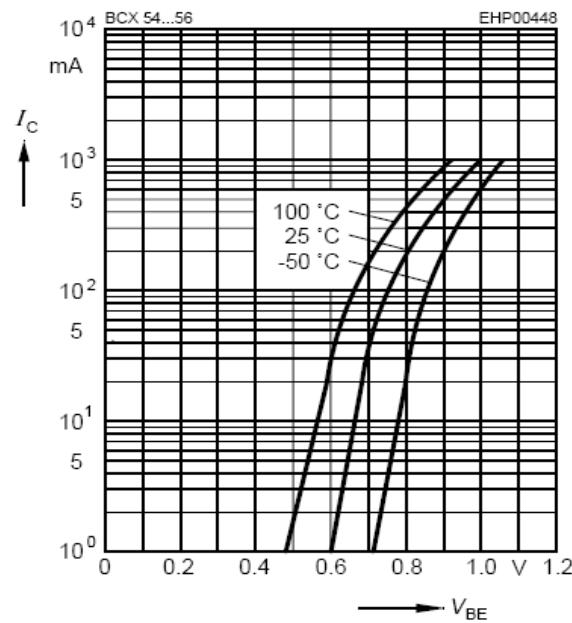
Total power dissipation  $P_{\text{tot}} = f(T_S)$ 

Transition frequency  $f_T = f(I_C)$ 
 $V_{\text{CE}} = 10\text{V}$ 


**Permissible pulse load**

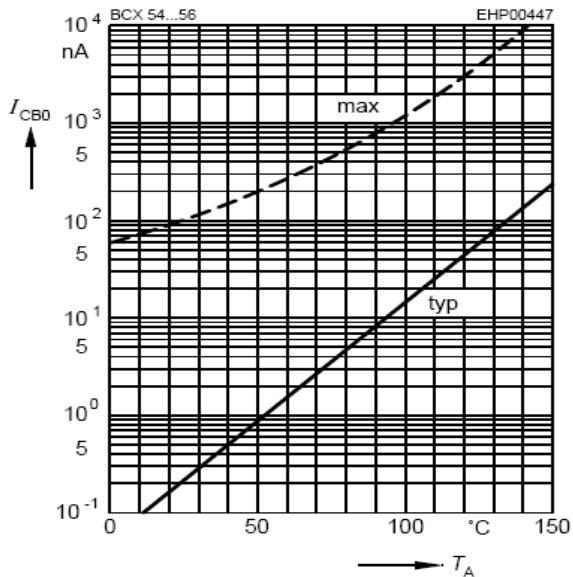
$$P_{\text{totmax}} / P_{\text{totDC}} = f(t_p)$$


**Collector current  $I_C = f(V_{BE})$** 

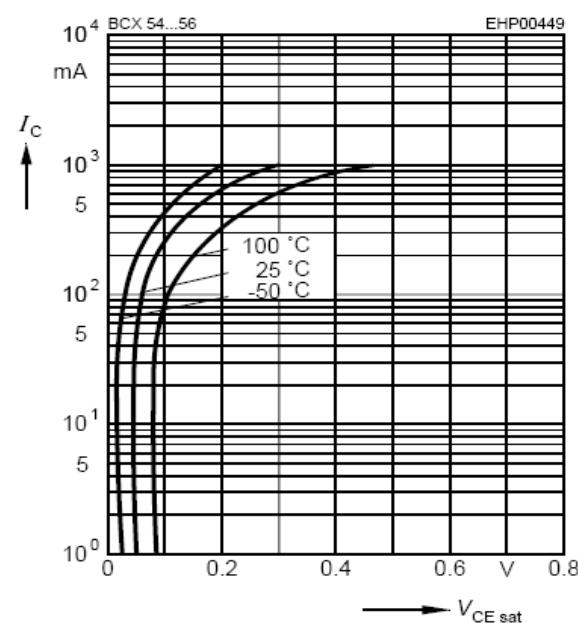
$$V_{CE} = 2V$$


**Collector cutoff current  $I_{CBO} = f(T_A)$** 

$$V_{CB} = 30V$$

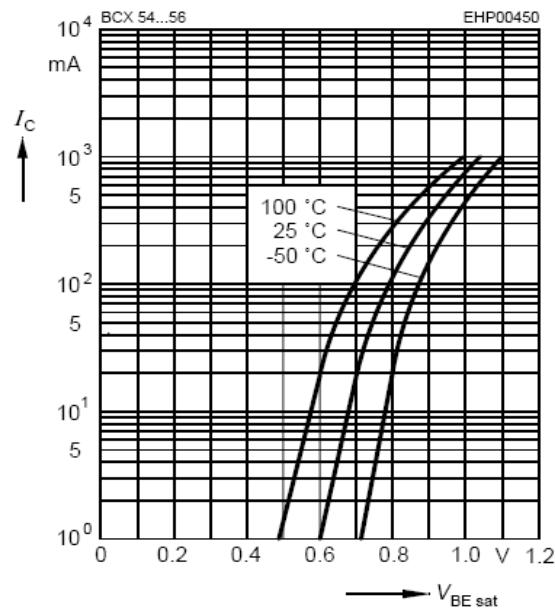

**Collector-emitter saturation voltage**

$$I_C = f(V_{CE\text{sat}}), h_{FE} = 10$$



**Base-emitter saturation voltage**

$$I_C = f(V_{BEsat}), h_{FE} = 10$$


**DC current gain  $h_{FE} = f(I_C)$** 

$$V_{CE} = 2V$$

